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# Miscellaneous Useful Material

#### Constants

 $N_{\rm A} = 6.022 \cdot 10^{23} \, \rm mol^{-1}$ 

 $\alpha \approx 1/137$ 

 $m_e c^2 \approx 511 \, \mathrm{keV}$ 

 $m_{\rm p}c^2 \approx 938\,{\rm keV}$ 

 $m_{\rm n}c^2 \approx 940\,{\rm MeV}$ 

 $m_{\pi} \approx 140 \, \mathrm{MeV}$ 

 $m_{\rm K} \approx 500 \, {\rm MeV}$ 

 $K_{\rm BB} \approx 0.3 \, {\rm MeV \, g^{-1} \, cm^2}$ 

 $(\beta\gamma)_{\rm MIP} \approx 3.5$ ,  $\beta_{\rm MIP} \approx 0.96$ 

 $1 \text{ torr} = 1 \text{ mmHg} \approx 133 \text{ Pa}$ 

 $k_B T|_{T=300 \text{ K}} \approx 0.025 \text{ eV}$ 

## Some Relationships from Special Relativity

$$\beta \equiv v/c$$
  $\gamma \equiv 1/\sqrt{1-\beta^2}$ 

$$E^2 = m^2 c^4 + p^2 c^2$$
  $E = \gamma mc^2$   $E = T + mc^2$ 

$$\gamma\beta = \frac{pc}{mc^2}$$
  $\gamma^2 = 1 + (\beta\gamma)^2$   $\beta^2 = 1 - 1/\gamma^2$ 

$$\beta^2 = \frac{p^2 c^2}{m^2 c^4 + p^2 c^2}$$

$$mc^2 = \frac{p^2c^2 - T^2}{2T}$$

#### Some Relationships from Chemistry

The number density  $n_a$  ( $n_e$ ) of atoms (electrons) in material with density  $\rho$ , molar mass  $M_{\rm m}$  and atomic number Z is...

$$n_{\rm a} = \frac{\rho N_{\rm A}}{M_{\rm m}}$$
 and  $n_{\rm e} = Z n_{\rm a}$ 

Molar mass  $M_{\mathrm{m}}$  and relative atomic mass  $A_{\mathrm{r}}$  are related by...

 $M_{\rm m} = A_{\rm r} M_{\rm u}$ , where  $M_{\rm u} \equiv 1 \, {\rm g \, mol}^{-1}$ 

$$n_{\rm a} \approx \frac{\rho N_{\rm A}}{AM_{\rm c}}$$
 (if  $A_{\rm r} \approx A$ )

#### Ideal Gas

 $\overline{V_{\rm m}} \approx 22.4 \, \mathrm{L} \, \mathrm{mol}^{-1}$ (molar volume of ideal gas at STP)

 $p_0 = 1 \, \text{atm} \approx 101 \, \text{kPa}$ (atmospheric pressure)

 $n = \frac{N_{\rm A}}{V_{\rm m}} \frac{p}{p_0}$ (number density of ideal gas molecules)

#### **Statistics**

Binomial distribution: the probability of n events occurring over the course of N trials, where the probability of an event occurring in a single trial is p, is given by

$$P(n|N,p) = \binom{N}{n} p^n (1-p)^{N-n} = \frac{N!}{n!(N-n)!} p^n (1-p)^{N-n}$$

Poisson distribution: the probability of n independent random events occurring in the time interval T, where the probability for an event per unit time is  $\lambda$ , is

$$\begin{split} &P(n|\lambda,T) = \frac{(\lambda T)^n}{n!} e^{-\lambda T}, \; \text{ or}... \\ &P(n|\mu) = \frac{\mu^n e^{-\mu}}{n!}, \quad \text{where } \mu \equiv \lambda T \\ &\langle X \rangle = \sigma_X^2 = \lambda \qquad \text{(if $X$ is Poisson distributed with mean $\mu$)} \end{split}$$

Error function and standard normal distribution CDF

$$\Phi(x) = \frac{1}{2} \left[ 1 + \operatorname{erf}\left(\frac{x}{\sqrt{2}}\right) \right]$$

Statistical significance in signal/background classification

$$n = \frac{N_{\rm sig}}{\sigma_{\rm bg}}$$

 $n = \frac{N_{\rm sig}}{\sigma_{\rm bg}}$   $N_{\rm sig}$  is number of counted signal events  $\sigma_{\rm b}$  is fluctuatio in background events

$$\overline{N}_{\rm sig} = st$$
  $\overline{N}_{\rm bg} = bt$  (if rates  $s, b$  are known)

#### Interaction of Particles and Matter

### Scattering Cross Section

Beam with flux F of incident particles on target;  $\frac{dN_s}{d\Omega}$  is number of particles scattered into solid angle  $d\Omega$  per unit time.

$$\frac{d\sigma}{d\Omega} = \frac{1}{F} \frac{dN_s}{d\Omega}$$
  $\sigma_{\text{tot}}(E) = \iint_{\Omega} \frac{d\sigma}{d\Omega} d\Omega$ 

$$N_{\rm s}(\Omega) = F S n_{\rm t} \frac{{
m d}\sigma}{{
m d}\Omega} \delta x$$
  $N_{\rm s} = F S n_{\rm t} \sigma_{\rm tot} \delta x$ 

$$\begin{aligned} \mathrm{d}P_{\mathrm{scat}} &= n_{\mathrm{t}}\sigma_{\mathrm{tot}}\,\mathrm{d}x & \text{(probability for scattering in region d}x) \\ P(x+\mathrm{d}x) &= P(x)\cdot(1-\mathrm{d}P_{\mathrm{scat}}) = P(x)(1-n_{\mathrm{t}}\sigma_{\mathrm{tot}}\,\mathrm{d}x) \\ P(x) &= e^{-n_{\mathrm{t}}\sigma_{\mathrm{tot}}x} & \text{(probability for not scattering up to }x) \end{aligned}$$

$$1 \, \mathrm{b} = 10^{-24} \, \mathrm{cm}^2 = 10^{-28} \, \mathrm{m}^2$$

## Charged Particles in Matter

Charged ionizing particle (IP) of mass m and valence  $Z_p$  travels through material with atomic number  $Z_{\rm m}$  and density  $\rho$ . Assume IP is heavy  $(m \gg m_e)$ 

Energy loss occurs primarily because of inelastic collisions of IP with electrons in the material.

#### Bethe-Bloch Formula

Valid for  $\beta \gamma \sim (0.5, 10^3)$ 

$$-\frac{\mathrm{d}E}{\mathrm{d}x} = \frac{4\pi}{m_{\mathrm{e}}c^2} \cdot \frac{n_{\mathrm{e}}Z_{\mathrm{p}}^2}{\beta^2} \cdot \left(\frac{e_0^2}{4\pi\epsilon_0}\right)^2 \ln\left[\left(\frac{2m_{\mathrm{e}}c^2\gamma^2\beta^2}{Z_{\mathrm{m}}I_0}\right) - \beta^2\right]$$
$$= K \cdot \frac{\rho Z_{\mathrm{m}}}{A} \cdot \frac{Z_{\mathrm{p}}^2}{\beta^2} \left[\ln\left(\frac{2m_{\mathrm{e}}c^2\beta^2\gamma^2}{Z_{\mathrm{m}}I_0}\right) - \beta^2\right]$$

 $K \approx 0.3 \,\mathrm{MeV}\,\mathrm{g}^{-1}\,\mathrm{cm}^2$ 

Small  $\beta$  approximation (e.g. for  $\beta \gamma \lesssim 1$ ) produces...

$$-\frac{\mathrm{d}E}{\mathrm{d}x} \sim \beta^{-2} \sim T^{-1} \implies \frac{\mathrm{d}T}{\mathrm{d}x} = -\frac{k}{T}, \qquad k = -T_0 \frac{\mathrm{d}T}{\mathrm{d}x} \Big|_{T=T_0}$$

#### In Polyatomic Substances

Example: for  $H_2O_4$ ,  $i \in \{H, O\}$ , e.g.  $a_H = 2$ ,  $a_O = 4$ 

$$Z \to Z_{\text{eff}} = \sum_i a_i Z$$

$$A \to A_{\text{eff}} = \sum_{i} a_i A_i$$

$$Z o Z_{ ext{eff}} = \sum_{i} a_{i} Z_{i}$$
  
 $A o A_{ ext{eff}} = \sum_{i} a_{i} A_{i}$   
 $\ln I o \ln I_{ ext{eff}} = \sum_{i} \frac{a_{i} Z_{i} \ln I_{i}}{Z_{ ext{eff}}}$ 

$$\left(-\frac{\mathrm{d}E}{\mathrm{d}x}\right)_{\mathrm{tot}} = \sum_{i} w_{i} \frac{\mathrm{d}E}{\mathrm{d}x} \bigg|_{i}, \quad w_{i} = \sum_{j} \frac{a_{i}A_{i}}{a_{j}A_{j}}$$

$$\left(-\frac{\mathrm{d}E}{\mathrm{d}x}\right)_{\mathrm{tot}} = K \cdot \frac{\rho_{\mathrm{tot}} Z_{\mathrm{eff}}}{A_{\mathrm{eff}}} \cdot \frac{Z_{\mathrm{p}}^{2}}{\beta^{2}} \left[ \ln \left( \frac{2m_{\mathrm{e}}c^{2}\beta^{2}\gamma^{2}}{I_{\mathrm{eff}}} \right) - \beta^{2} \right]$$

### Photons in Matter

Three processes: photoelectric effect, Compton scattering, and pair production

$$\begin{split} & \sigma_{\gamma} = \sigma_{\mathrm{pe}} + Z \cdot \sigma_{\mathrm{C}} + \sigma_{\mathrm{pair}} \\ & \sigma_{\mathrm{pe}} \sim \frac{Z^{n}}{E_{\gamma}^{7/2}}, \ n \lesssim [4, 5] \\ & j(x) = j_{0}e^{-\mu x} \quad \mu_{\gamma} = n_{\mathrm{a}}\sigma_{\gamma} = \frac{\rho N_{\mathrm{A}}}{M_{\mathrm{m}}}\sigma_{\gamma} \quad \lambda_{\gamma} = 1/\mu_{\gamma} \\ & \mu_{\mathrm{tot}} = \sum_{i} w_{i}\mu_{i} = \sum_{i} \left(\frac{A_{i}}{\sum_{i} A_{j}}\right) \mu_{i} \quad \text{(polyatomic substances)} \end{split}$$

#### Compton Scattering

Incident and scattered  $\gamma$  energies:  $E_{\gamma}, E'_{\gamma}$ ;  $\theta$  scattering angle

$$\begin{split} \frac{E_{\gamma}'}{E_{\gamma}} &= \frac{1}{1 + \alpha(1 - \cos\theta)}, \qquad \alpha \equiv \frac{E_{\gamma}}{m_{\rm e}c^2} \\ \frac{{\rm d}\sigma}{{\rm d}\Omega} &= \frac{r_{\rm e}^2}{2} \left(\frac{E_{\gamma}'}{E_{\gamma}}\right)^2 \left[\frac{E_{\gamma}'}{E_{\gamma}} + \frac{E_{\gamma}}{E_{\gamma}'} - \sin^2\theta\right] \\ \sigma_{\rm C} &= \frac{8\pi r_{\rm e}^2}{3} \left[\frac{1 - 2\alpha + 1.2\alpha^2}{(1 + 2\alpha)^2}\right], \quad r_{\rm e} &= \frac{1}{4\pi\epsilon_0} \frac{\epsilon_0}{m_{\rm e}c^2} \sim 2.8\,{\rm fm} \\ \frac{{\rm d}\sigma_{\rm C}}{{\rm d}T} &= \frac{\pi r_0^2}{m_{\rm e}c^2\alpha^2} \left[2 + \frac{s^2}{\alpha^2(1 - s)^2} + \frac{s}{1 - s}\left(s - \frac{2}{\alpha}\right)\right], \quad s = T/E_{\gamma} \end{split}$$

## Particle Detectors

#### **Energy Resolution**

For a particle depositing energy  $E_{\rm dep}$  and producing N ion pairs in a detector with Fano factor F...

$$\mathcal{R} \equiv rac{\sigma_{E_{ ext{dep}}}}{E_{ ext{dep}}} = rac{\sigma_{N}}{N}$$

Particle passes through detector:  $\sigma_N = \sqrt{N}$ 

Particle stops inside detector:  $\sigma_N = \sqrt{FN}$ 

$$N = \frac{E_{\text{dep}}}{w_{\text{i}}} \implies \mathcal{R} = \sqrt{\frac{w_{\text{i}}}{E_{\text{dep}}}} \text{ or } \mathcal{R} = \sqrt{\frac{Fw_{\text{i}}}{E_{\text{dep}}}}$$

### **Ionization-Based Detectors**

#### Parallel-Plate Ionization Cell

Consider a parallel-plate cell with pressure p, spacing d, potential difference U and constant electric field E = U/d.

$$dW = qE dx = \frac{qU}{d} dx \qquad \text{(work on a charge } q\text{)}$$

$$dW_{\rm C} = CU dU$$
 (change in capacitor energy)

$$dW = dW_{\rm C} \implies dU = \frac{q}{C} \frac{dx}{d}$$

$$v_{\rm d} = \frac{E\mu}{p}$$
 (drift velocity, mobility)

$$\Delta U(t) = \frac{q}{C} \frac{\mu}{pd} Et$$
 (before all ions reach electrodes)

$$\Delta U = \frac{Q}{C}$$
 (when total charge Q reaches electrodes)

#### **Multiplication Factor**

For an incident particle freeing  $N_0$  primary ions, which in turn free an average of N secondary ions...

$$M \equiv \frac{N}{N_0}$$
 (multiplication factor)

 $\lambda$  is electron mean free path for ionizing collisions

 $\alpha \equiv 1/\lambda$  is probability for ionization per distance traveled

$$dN = N\alpha dx \implies N(x) = N_0 e^{\alpha x}$$
 (for N initial electrons)

$$M(x) \equiv N/N_0 = e^{\alpha x}$$
 or  $M = \exp\left(\int_{x_1}^{x_2} \alpha(x) dx\right)$ 

In a cell at pressure p with electric field E...

$$\alpha = Ape^{-\frac{Bp}{E}}$$
 (Townsend discharge model; A, B given)

#### Cylindrical Ionization Chamber

For a cylindrical chamber with outer radius R and a node wire radius  $r_0$  at voltage  $U_0...$ 

$$E(r) = \frac{U_0}{\ln(R/r_0)} \frac{1}{r} \quad \phi(r) = -\frac{U_0}{\ln(R/r_0)} \ln \frac{r}{r_0} \quad C = \frac{2\pi\epsilon_0 L}{\ln(R/r_0)}$$

$$v_{\rm d} = E\mu$$
 (drift velocity  $v_{\rm d}$ , mobility  $\mu$ )

Signal detection delay  $t_{\text{sig}}$  between ionization event at  $r = r^*$  and primary electrons reaching anode wire is...

$$t_{\rm sig} = \frac{\ln(R/r_0)R^2}{2\mu_{\rm e}U_0} \left[ \left(\frac{r^*}{R}\right)^2 - \left(\frac{r_0}{R}\right)^2 \right] \approx \frac{\ln(R/r_0)}{2\mu_{\rm e}U_0} (r^*)^2$$

Only secondary positive ions contribute appreciably to signal

$$U(t) = -\frac{Q_{\rm i}}{4\pi\epsilon_0 L} \ln\left[1 + \frac{\mu_{\rm i} C U_0}{\pi\epsilon_0 L r_0^2} \cdot (t - t_{\rm sig})\right] \equiv -\frac{Q_{\rm i}}{4\pi\epsilon_0 L} \ln\left(1 + \frac{t - t_{\rm sig}}{t_0}\right)$$

$$U(t) = -\frac{N_{\rm s}e_0}{4\pi\epsilon_0 L} \begin{cases} \approx 0 & t < t_{\rm sig} \\ \ln\left(1 + \frac{t - t_{\rm sig}}{t_0}\right) & t_{\rm sig} < t < t_{\rm sig} + t_{\rm ion}. \end{cases}$$

$$t_0 \equiv \frac{\pi \epsilon_0 L r_0^2}{\mu_i C U_0}, \qquad t_{\text{ion}} \approx \frac{\ln(R/r_0)}{2\mu_i U_0} R^2$$

$$N_{\rm s} = M N_{\rm p} = M \frac{E_{\rm dep}}{w_{\rm s}}$$

## Measuring Momentum

Use a central drift chamber with beamline axis  $\hat{\bf z}$  and magnetic field  ${\bf B}\approx B\,\hat{\bf e}_z$ 

For particle of charge q with trajectory curvature radius R...

$$\frac{mv_{\rm T}^2}{R} = qv_{\rm T}B \implies p_{\rm T} = qBR$$
 (very simplified)

 $p_{\mathrm{T}}c \approx (0.3qBR)\,\mathrm{GeV}$  ...

... if q is measured in  $e_0$ , B in tesla and R in meters

Momentum resolution  $\sigma_{p_{\rm T}}$  if trajectory resolution is  $\sigma_x$ ...

$$\frac{\sigma_{p_{\rm T}}}{p_{\rm T}} \approx \frac{\sqrt{96}\sigma_x}{qBL^2} \cdot p_{\rm T}$$
 (three points on trajectory)

$$\frac{\sigma_{p_{\rm T}}}{p_{\rm T}} \approx \frac{\sigma_x}{qBL^2} \cdot \sqrt{\frac{720}{N+4}} \cdot p_{\rm T}$$
 (N points on trajectory)

L is characteristic length of cylindrical drift chamber

### Semiconducting Detectors

 $E_{\rm v}$  is top of valence band

 $E_{\rm c}$  is bottom of conduction band

 $E_{\rm g} \equiv E_{\rm c} - E_{\rm v}$  is band gap

$$f(E) = \frac{1}{e^{\beta(E-\mu)}+1}$$
 (Fermi-Dirac distribution)

$$g_{\rm c}(E) pprox rac{1}{2\pi^2} \left(rac{2m_{
m c}^*}{\hbar^2}
ight)^{3/2} \sqrt{|E-E_{
m c}|}$$

$$g_{\rm v}(E) pprox rac{1}{2\pi^2} \left( rac{2m_{
m v}^*}{\hbar^2} 
ight)^{3/2} \sqrt{|E - E_{
m v}|}$$

$$n_{\rm c} = \frac{1}{4} \left( \frac{2 m_{\rm c}^* k_B T}{\pi \hbar^2} \right)^{3/2} e^{-\beta (E_{\rm c} - \mu)} \equiv N_{\rm c}(T) e^{-\beta (E_{\rm c} - \mu)}$$

$$p_{\rm v} = \frac{1}{4} \left( \frac{2m_{\rm v}^* k_B T}{\pi \hbar^2} \right)^{3/2} e^{-\beta(\mu - E_{\rm v})} \equiv P_{\rm v}(T) e^{-\beta(\mu - E_{\rm v})}$$

In instrinsic SC:  $n_{\rm c}=p_{\rm v}\equiv n_{\rm i} \implies n_{\rm i}^2=N_{\rm c}P_{\rm v}e^{-\beta E_{\rm g}}$ 

$$n_{\rm i} = \frac{1}{4} \left( \frac{2k_B T \sqrt{m_{\rm e}^* m_{\rm h}^*}}{\pi \hbar^2} \right)^{3/2} e^{-\frac{\beta E_{\rm g}}{2}}$$

## Resistivity, Conductivty, Current Density

Consider conductor of conductivity  $\sigma_{\rm E}$  with number density n of charge carriers q and mobility  $\mu$  moving at drift velocity  $v_{\rm d}$  under external electric field E

$$j = \sigma_{\rm E} E$$
 and  $j = nq v_{\rm d}$ 

$$v_d = \mu E$$

$$\rho_{\rm E} \equiv \frac{1}{\sigma_{\rm E}}; \qquad \rho_{\rm E} = \frac{1}{nq\mu} \qquad \sigma_{\rm E} = nq\mu$$

$$j = e_0 n_i (\mu_e + \mu_h) E$$
 (in instrinsic SC)

$$j_{\rm n} \approx e_0 N_{\rm d} \mu_{\rm e} E, \quad j_{\rm p} \approx e_0 N_{\rm a} \mu_{\rm h} E$$

$$\sigma_{
m n}pprox e_0 N_{
m d}\mu_{
m e}, \quad \sigma_{
m p}pprox e_0 N_{
m a}\mu_{
m h} \qquad \qquad {
m (in doped Se}$$

## p-n Junction

Join p- and n-type SCs with dopant densities  $N_{\rm a}$  and  $N_{\rm d}$ 

Depletion region spans  $x \in (-x_{\rm p}, x_{\rm n})$ 

$$N_{\rm a}x_{\rm p} = N_{\rm d}x_{\rm n}$$
 (conservation of charge)

$$\frac{\partial^2 \phi}{\partial x^2} = -\frac{\rho(x)}{\epsilon \epsilon_0}$$
 (Poisson equation for potential)

$$\rho(x) \approx \begin{cases} -e_0 N_{\rm a} & x \in (-x_{\rm p}, 0) \\ e_0 N_{\rm d} & x \in (0, x_{\rm n}) \end{cases}$$

$$\frac{\mathrm{d}\phi}{\mathrm{d}x} \approx \begin{cases} \frac{e_0 N_\mathrm{a}}{\epsilon \epsilon_0} (x + x_\mathrm{p}) & x \in (-x_\mathrm{p}, 0) \\ -\frac{e_0 N_\mathrm{d}}{\epsilon \epsilon_0} (x - x_\mathrm{n}) & x \in (0, x_\mathrm{n}). \end{cases}$$

$$\phi(-x_p) \equiv 0 \text{ V}, \quad V_0 \equiv \phi(x_n) - \phi(-x_p) = \phi(x_n)$$

$$V_0 = \frac{e_0}{2\epsilon\epsilon_0} \left( N_{\rm d} x_{\rm n}^2 + N_{\rm a} x_{\rm p}^2 \right)$$

$$\phi(x) = \begin{cases} \frac{e_0 N_{\rm a}}{2\epsilon\epsilon_0} (x+x_{\rm p})^2 & x \in (-x_{\rm p},0) \\ V_0 - \frac{e_0 N_{\rm d}}{2\epsilon\epsilon_0} (x-x_{\rm n})^2 & x \in (0,x_{\rm n}) \end{cases}$$

$$x_{\mathrm{n}}^2 = \tfrac{2\epsilon\epsilon_0 V_0}{e_0 N_{\mathrm{d}} \left(1 + \tfrac{N_{\mathrm{d}}}{N_{\mathrm{a}}}\right)} \qquad x_{\mathrm{p}}^2 = \tfrac{2\epsilon\epsilon_0 V_0}{e_0 N_{\mathrm{d}} \left(1 + \tfrac{N_{\mathrm{a}}}{N_{\mathrm{d}}}\right)}$$

$$d_{\rm pn}=x_{\rm n}+x_{\rm p}=\sqrt{\frac{2\epsilon\epsilon_0V_0}{e_0}\frac{N_{\rm a}+N_{\rm d}}{N_{\rm a}N_{\rm d}}}$$

$$d_{\rm pn} \approx x_{\rm n} \approx \sqrt{\frac{2\epsilon\epsilon_0 V_0}{e_0 N_{\rm d}}} \qquad ({\rm if} \ N_{\rm a} \gg N_{\rm d})$$

$$d_{
m pn} pprox x_{
m p} pprox \sqrt{rac{2\epsilon\epsilon_0 V_0}{e_0 N_{
m a}}} \qquad ({
m if}\ N_{
m d} \gg N_{
m a})$$

$$d_{\rm pn}^{\rm (b)} = d_{\rm pn}^{\rm (0)} \sqrt{1 + \frac{V_{\rm b}}{V_{\rm 0}}} \qquad \qquad ({\rm with~reverse~bias~voltage~} V_{\rm b})$$

## Approximate Expressions Depletion Region Width

$$\sigma_{\rm n} \approx e_0 N_{\rm d} \mu_{\rm e}, \ \sigma_{\rm p} \approx e_0 N_{\rm a} \mu_{\rm h} \ \Longrightarrow \ \rho_{\rm n} \approx \frac{1}{e_0 N_{\rm d} \mu_{\rm e}}, \ \rho_{\rm p} \approx \frac{1}{e_0 N_{\rm a} \mu_{\rm h}}$$

$$d_{\rm pn} \approx \sqrt{2\epsilon\epsilon_0 \rho_{\rm n} \mu_{\rm e} V_0}$$
 (if  $N_{\rm a} \gg N_{\rm d}$ )

$$d_{\rm pn} \approx \sqrt{2\epsilon\epsilon_0 \rho_{\rm p} \mu_{\rm h} V_0}$$
 (if  $N_{\rm d} \gg N_{\rm a}$ )

Using  $\epsilon_{\rm Si} \approx 12$  and  $\epsilon_{\rm Ge} \approx 16$  we get...

$$d_{\rm Si} \approx 0.53 \sqrt{\rho_{\rm n} V_0} \cdot \mu \text{m}$$
 (if  $N_{\rm a} \gg N_{\rm d}$ )

$$d_{\rm Si} \approx 0.32 \sqrt{\rho_{\rm p} V_0} \cdot \mu \text{m}$$
 (if  $N_{\rm d} \gg N_{\rm a}$ )

$$d_{\rm Ge} \approx 1.00 \sqrt{\rho_{\rm n} V_0} \cdot \mu \text{m}$$
 (if  $N_{\rm a} \gg N_{\rm d}$ )

$$d_{\rm Ge} \approx 0.65 \sqrt{\rho_{\rm p} V_0} \cdot \mu \text{m}$$
 (if  $N_{\rm d} \gg N_{\rm a}$ )

... assuming  $V_0$  in volts and  $\rho$  in  $\Omega$  cm

## Signal Dynamics in a p-n Semiconducting Detector

Shift coordinate system so that  $x_p \equiv 0$ 

Let  $x_0$  denote initial position of electron-hole pair

$$au_{
m h} \equiv rac{\epsilon \epsilon_0}{e_0 \mu_{
m h} N_{
m e}}, \qquad au_{
m e} \equiv rac{\mu_{
m h}}{\mu_{
m e}} au_{
m h}, \qquad t_{
m e} = au_{
m h} rac{\mu_{
m h}}{\mu_{
m e}} \cdot \ln rac{d_{
m pn}}{x_0}$$

$$Q_{\rm e}(t) = +\frac{e_0}{d_{\rm pn}} x_0 \left(1 - e^{\frac{\mu_{\rm e}}{\mu_{\rm h}} \frac{t}{\tau_{\rm h}}}\right)$$
 (for  $t < t_{\rm e}$ )

$$Q_{\rm h}(t) = -\frac{e_0}{d_{\rm pn}} x_0 \left(1 - e^{-t/\tau_{\rm h}}\right)$$

$$I_{\rm e}(t) = \frac{{\rm d}Q_{\rm e}}{{\rm d}t} = -\frac{e_0}{d_{\rm nn}} \frac{x_0}{T_{\rm h}} \frac{\mu_{\rm e}}{\mu_{\rm h}} \frac{t}{\tau_{\rm h}}$$
 (for  $t < t_{\rm e}$ )

$$I_{\rm h}(t) = \frac{\mathrm{d}Q_{\rm h}}{\mathrm{d}t} = \frac{e_0}{d_{\rm pn}} \frac{x_0}{\tau_{\rm h}} e^{-t/\tau_{\rm h}}$$

$$I_0^{\rm h} \equiv \frac{e_0}{d_{\rm pp}} \frac{x_0}{\tau_{\rm h}}, \qquad I_0^{\rm e} \equiv -\frac{e_0}{d_{\rm pp}} \frac{x_0}{\tau_{\rm e}}$$

$$U_{\rm e}(t) = \frac{I_{\rm 0}^{\rm e}R}{1 + (RC)/\tau_{\rm e}} \begin{cases} e^{t/\tau_{\rm e}} - e^{-\frac{t}{RC}} & t < t_{\rm e} \\ \left(e^{t_{\rm e}/\tau_{\rm e}} - e^{-\frac{t_{\rm e}}{RC}}\right) e^{-\frac{(t-t_{\rm e})}{RC}} & t > t_{\rm e}. \end{cases}$$

$$U_{\rm h}(t) = \frac{I_0^{\rm h} R}{1 - (RC)/\tau_{\rm h}} \left( e^{-t/\tau_{\rm h}} - e^{-\frac{t}{RC}} \right),$$

### Limit Cases of Electron Signal

$$U_{\rm e}(t) \approx I_0^{\rm e} R \begin{cases} e^{t/\tau_{\rm e}} - e^{-\frac{t}{RC}} & t < t_{\rm e} \\ \left(e^{t_{\rm e}/\tau_{\rm e}} - e^{-\frac{t_{\rm e}}{RC}}\right) e^{-\frac{(t-t_{\rm e})}{RC}} & t > t_{\rm e} \end{cases}$$
 (RC  $\ll \tau_{\rm e}$ )

$$U_{\rm e}(t) = \frac{I_{\rm e}^0 \tau_{\rm e}}{C} \left(e^{t_{\rm e}/\tau_{\rm e}} - 1\right) e^{-\frac{(t-t_{\rm e})}{RC}} = \frac{Q_{\rm e}(t_{\rm e})}{C} e^{-\frac{(t-t_{\rm e})}{RC}} \quad (RC \gg \tau_{\rm e})$$

#### Position Measurement

Consider parallel silicon microstrips separated by pitch p

$$\sigma_x = \frac{p}{\sqrt{12}}$$
 (when using one strip to measure position)

$$\overline{x} = \frac{\sum_{i} Q_i x_i}{\sum_{i} Q_i}$$
 (using multiple strips to measure position)

$$\sigma_{\overline{x}}^2 \propto p^2 \frac{\sum_{j} \sigma_{Q_j}^2}{\left(\sum_{i} Q_i\right)^2} = p^2 \frac{(\text{noise})^2}{(\text{signal})^2} = \frac{p^2}{\text{SNR}^2}$$

 $Q_j$  is charge on j-th strip  $\sigma_{Q_i}^2$  is resolution of charge on j-th strip

## **Scintillating Detectors**

Consider scintillator with time constant  $\tau$ , emitting  $Y \equiv \frac{\mathrm{d}N}{\mathrm{d}E}$  photons per unit absorbed energy and photodetector with efficiency  $\eta$  and multiplication factor M

$$\eta \equiv E_{\rm scint}/E_{\rm dep}, \quad E_{\rm scint} = N_{\rm scint}h\nu = hc/\lambda$$
 (efficiency)

$$N(t) = N_0 e^{-t/\tau}$$
 (number of scintillation photons)

We assume a fast photodetector, so I(t) follows N(t), i.e.

$$I(t) = I_0 e^{-t/\tau}$$
 (photodetector current)

$$Q = \eta e_0 M Y E_{\text{dep}} \qquad \text{(photodetector charge)}$$

$$Q = \int_0^\infty (t) dt = I_0 \tau \implies I_0 \tau = \eta e_0 M Y E_{\text{dep}}$$

$$U(t) = \frac{I_0 R}{1 - (RC)/\tau} \left( e^{-t/\tau} - e^{-\frac{t}{RC}} \right)$$

$$U(t) \approx \frac{I_0 \tau}{C} e^{-t/RC} = \frac{Q}{C} e^{-t/(RC)}$$
 (RC  $\gg \tau$ )

$$U(t) \approx RI_0 e^{-t/\tau} = RI(t)$$
 (RC  $\ll \tau$ )

#### Fluctuations in Photomultipliers

X is the number of secondary electrons reaching PMT anode as a result of one initial cathode photoelectron

n is the number of initial cathode photoelectrons

S is the sum of all secondary electrons reaching PMT anode

n is Poisson-distributed with mean  $\lambda$ 

$$\langle S \rangle = \lambda \langle X \rangle$$

$$\sigma_S^2 = \lambda \left\langle X^2 \right\rangle \left( 1 + \frac{\sigma_X^2}{\langle X \rangle^2} \right) \equiv F \lambda \left\langle X^2 \right\rangle$$

### **Neutron Detection**

In a material with scattering center density  $n_s$  and neutron cross section  $\sigma$ ...  $\lambda = \frac{1}{n \cdot \sigma}$ 

In a material of width d with neutron MFP  $\lambda$ , probability for one neutron interaction is...  $P = \int_0^d \frac{1}{\lambda} e^{-\frac{x}{\lambda}} dx$ 

### Post-Scattering Energy Distribution of Fast Neutrons

Consider fast neutron with initial energy  $E \gg k_B T$  scattering from a nucleus with mass number A at angle  $\theta$ 

Assume isotropic scattering  $\frac{d\sigma}{d\Omega} = \frac{\sigma_{\rm tot}}{4\pi}$ 

$$\alpha \equiv \frac{(A-1)^2}{(A+1)^2}$$

$$\frac{E'}{E} = \frac{A^2 + 2A\cos\theta + 1}{(A+1)^2}$$

$$E'_{\text{max}} = E, \quad E'_{\text{min}} = \alpha E$$

(bounds on E')

$$\frac{\mathrm{d}P}{\mathrm{d}E'} = \begin{cases} 0 & E' < \alpha E \\ \frac{1}{(1-\alpha)E} & E' \in (\alpha E, E) \\ 0 & E' > E. \end{cases}$$

(distribution of E')

### Slowing Neutrons to Thermal Energy

Goal: slow neutron from  $E_0 \gg k_B T$  to  $E_{\rm T} \sim k_B T$ 

$$\xi \equiv \left\langle \ln \tfrac{E_0}{E'} \right\rangle \implies \ln \tfrac{E'}{E_0} = -\xi \implies E' = E_0 e^{-\xi}$$

$$\xi = 1 + \frac{\alpha}{1-\alpha} \ln \alpha = 1 + \frac{(A-1)^2}{2A} \ln \frac{A-1}{A+1}$$

$$\xi \approx \frac{2}{A+2/3}$$
 (for heavy nuclei,  $A \gtrsim 10$ )

$$\overline{\xi} \equiv \frac{\sum_i \sigma_i \xi_i}{\sum_i \sigma_i}$$

(polyatomic materials)

$$E_N' = e^{-N\xi} E_0$$

(energy after N-th collision)

$$N = \frac{1}{\xi} \ln \frac{E_0}{E_{\mathrm{T}}}$$

(collisions to reach energy  $E_{\rm T}$ )

# Cherenkov Radiation

Consider particle with charge  $z = q/e_0$  moving along x axis in material with refractive index n at speed v > c/n

$$\cos \theta_{\rm C} = \frac{1}{n\beta} \implies \theta_{\rm C} = \cos^{-1} \frac{1}{n\beta}$$

(Cherenkov angle)

$$\beta > 1/n \text{ or } pc > \frac{mc^2}{\sqrt{1 - (1/n^2)}}$$
 (t

(thresholds for radiation)

$$\frac{\mathrm{d}^2 E}{\mathrm{d}x \, \mathrm{d}\omega} = z^2 \frac{\alpha \hbar \omega}{c} \sin^2 \theta_{\mathrm{C}}$$

$$\frac{\mathrm{d}^2 N}{\mathrm{d}x \, \mathrm{d}\omega} = \frac{z^2 \alpha}{c} \sin^2 \theta_{\mathrm{C}} = \frac{z^2 \alpha}{c} \left( 1 - \frac{1}{(n\beta)^2} \right)$$

$$\frac{\mathrm{d}^2 N}{\mathrm{d}x \,\mathrm{d}\lambda} = \frac{2\pi z^2 \alpha}{\lambda^2} \sin^2 \theta_{\mathrm{C}} = \frac{2\pi z^2 \alpha}{\lambda^2} \left( 1 - \frac{1}{(n\beta)^2} \right)$$

#### Cherenkov Detectors

Consider a detector sensitive to radiation in the range  $\lambda_{\min}$ ,  $\lambda_{\max}$  with efficiency  $\eta(\lambda)$ 

$$N_{\rm det} = d \int_{\lambda_{\rm min}}^{\lambda_{\rm max}} \eta(\lambda) \frac{\mathrm{d}^2 N}{\mathrm{d}x \, \mathrm{d}\lambda} \, \mathrm{d}\lambda$$

$$N_{\rm C} \propto \sin^2 \theta_{\rm C} = \left(1 - \frac{1}{(\beta n)^2}\right) \implies N_{\rm C} \to N_{\rm max} \text{ as } \beta \to 1$$

$$\langle N \rangle = \frac{N_{\rm max}}{1-1/n^2} \left(1 - \frac{1}{\beta^2 n^2}\right) \equiv a \left(1 - \frac{1}{\beta^2 n^2}\right)$$

$$\implies \beta = \frac{1}{n\sqrt{1 - \left(\langle N \rangle / a\right)}}$$